

### 600 V, 4 A Silicon Carbide Schottky Diode

#### **Features**

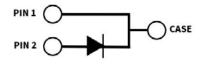
- 600-Volt Schottky rectifier
- Optimized for PFC boost diode application
- Zero reverse recovery current
- Zero forward recovery voltage
- High-frequency operation
- Temperature-independent switching behavior
- Extremely fast switching
- Positive temperature coefficient on V<sub>F</sub>

# 4





TO-252-2



Package Types: TO-252-2

PN: C3D04060

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### **Typical Applications**

- Switch mode power supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free wheeling diodes in inverter stages
- AC/DC converters

### **Benefits**

- Replace bipolar with unipolar rectifiers
- Essentially no switching losses
- Higher efficiency
- Reduction of heat sink requirements
- Parallel devices without thermal runaway

### **Maximum Ratings** (T<sub>c</sub> = 25 °C Unless Otherwise Specified)

| Parameter                                  | Symbol                            | Value       | Unit | Test Conditions  | Note   |  |
|--|-----------------------------------|-------------|------|--|--------|--|
| Repetitive Peak Reverse Voltage            | V <sub>RRM</sub>                  | 600         |      |  |        |  |
| Surge Peak Reverse Voltage                 | V <sub>RSM</sub>                  | 600         | V    |  |        |  |
| DC Blocking Voltage                        | V <sub>DC</sub>                   | 600         |      |  |        |  |
| Continuous Forward Current                 | I <sub>F</sub>                    | 13.5        | A    | T <sub>c</sub> = 25 °C   | Fig. 3 |  |
|  |                                   | 6           |      | T <sub>c</sub> = 135 °C  |        |  |
|  |                                   | 4           |      | T <sub>c</sub> = 155 °C  |        |  |
| Repetitive Peak Forward Surge Current      | I <sub>FRM</sub>                  | 17          |      | T <sub>C</sub> = 25 °C, t <sub>P</sub> = 10 ms, Half Sine Wave           |        |  |
|  |                                   | 12          |      | T <sub>c</sub> = 110 °C, t <sub>p</sub> = 10 ms, Half Sine Wave          |        |  |
| Non-Repetitive Peak Forward Surge Current  | I <sub>FSM</sub>                  | 25          |      | T <sub>C</sub> = 25 °C, t <sub>P</sub> = 10 ms, Half Sine Wave           | Fig. 8 |  |
|  |                                   | 19          |      | T <sub>c</sub> = 110 °C, t <sub>p</sub> = 10 ms, Half Sine Wave          |        |  |
| Non-Repetitive Peak Forward Surge Current  | I <sub>F, Max</sub>               | 220         |      | T <sub>C</sub> = 25 °C, t <sub>P</sub> = 10 μs, Pulse                    | Fig. 8 |  |
|  |                                   | 160         |      | $T_{c} = 110 {}^{\circ}\text{C},  t_{p} = 10 \mu\text{s},  \text{Pulse}$ |        |  |
| Power Dissipation                          | P <sub>tot</sub>                  | 52          | W    | T <sub>c</sub> = 25 °C   | T:- 4  |  |
|  |                                   | 22.5        |      | T <sub>C</sub> = 110 °C  | Fig. 4 |  |
| Diode dV/dt Ruggedness                     | dV/dt                             | 200         | V/ns | V <sub>R</sub> = 0-600 V   |        |  |
| i²t Value                                  | ∫i²dt                             | 3.1         | A²s  | $T_c = 25 {}^{\circ}\text{C},  t_p = 10  \text{ms}$                      |        |  |
|  |                                   | 1.8         |      | $T_{c} = 110 {}^{\circ}\text{C},  t_{p} = 10  \text{ms}$                 |        |  |
| Operating Junction and Storage Temperature | T <sub>J</sub> , T <sub>stg</sub> | -55 to +175 | °C   |  |        |  |

### **Electrical Characteristics**

| Parameter                 | Symbol         | Тур. | Max.   | Unit | Test Conditions  | Note   |
|---------------------------|----------------|------|--------|------|--|--------|
| Forward Voltage           | V <sub>F</sub> | 1.4  | 1.7    | V    | I <sub>F</sub> = 4 A, T <sub>J</sub> = 25 °C   | Fig. 1 |
|                           |                | 1.7  | 2.4    |      | I <sub>F</sub> = 4 A, T <sub>J</sub> = 175 °C  |        |
|                           |                | 5    | 25     |      | V <sub>R</sub> = 600 V, T <sub>J</sub> = 25 °C   | Fig. 2 |
| Reverse Current           | I <sub>R</sub> | 10   | 100 μΑ | μΑ   | V <sub>R</sub> = 600 V, T <sub>J</sub> = 175 °C  |        |
| Total Capacitive Charge   | Q <sub>c</sub> | 10   |        | nC   | $V_R = 400 \text{ V}, I_F = 4 \text{ A}$<br>$di/dt = 500 \text{ A}/\mu\text{S}$<br>$T_J = 25 \text{ °C}$ | Fig. 5 |
| Total Capacitance         | С              | 231  |        | pF   | $V_R = 0 \text{ V}, T_J = 25 \text{ °C}, f = 1 \text{ MHz}$  | Fig. 6 |
|                           |                | 18.5 |        |      | $V_R = 200 \text{ V}, T_J = 25 \text{ °C}, f = 1 \text{ MHz}$  |        |
|                           |                | 15   |        |      | V <sub>R</sub> = 400 V, T <sub>J</sub> = 25 °C, f = 1 MHz  |        |
| Capacitance Stored Energy | E <sub>c</sub> | 1.4  |        | μJ   | V <sub>R</sub> = 400 V   | Fig. 7 |

Note: This is a majority carrier diode, so there is no reverse recovery charge.

### **Thermal Characteristics**

| Parameter                                | Symbol          | Тур. | Unit | Note   |
|--|-----------------|------|------|--------|
| Thermal Resistance from Junction to Case | $R_{\theta JC}$ | 2.9  | °C/W | Fig. 9 |

### **Typical Performance**

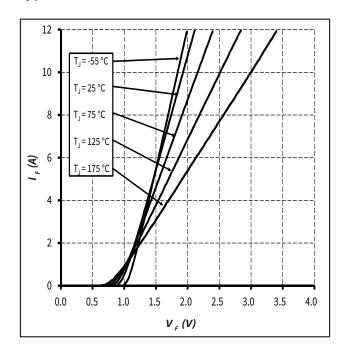
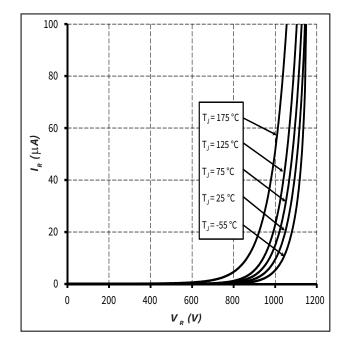


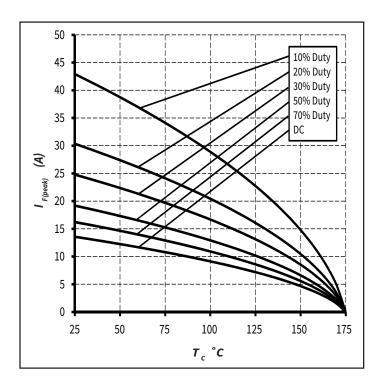
Figure 1. Forward Characteristics



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Figure 2. Reverse Characteristics

### **Typical Performance**



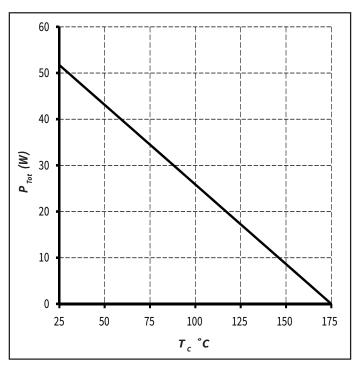
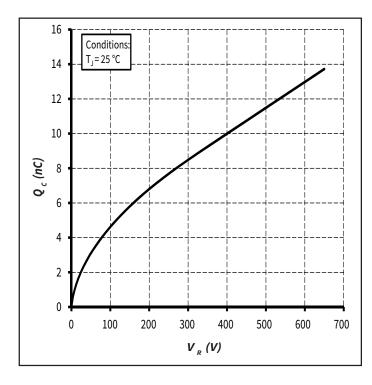


Figure 3. Current Derating

Figure 4. Power Derating





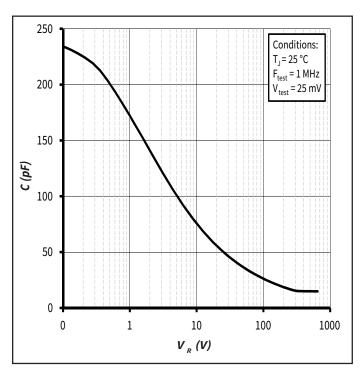
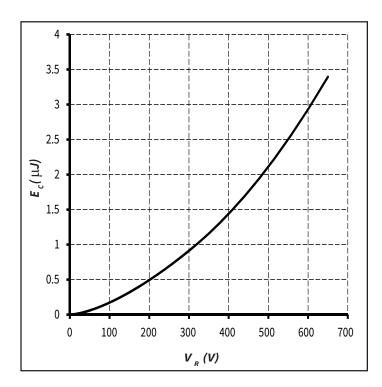


Figure 6. Capacitance vs. Reverse Voltage

## 4

### **Typical Performance**



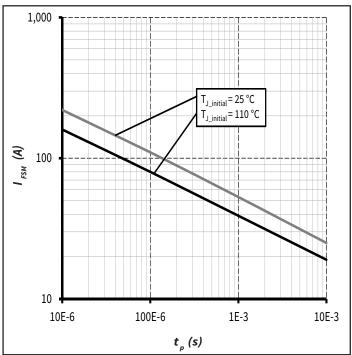


Figure 7. Capacitance Stored Energy

Figure 8. Non-Repetitive Peak Forward Surge Current Versus Pulse Duration (Sinusoidal Waveform)

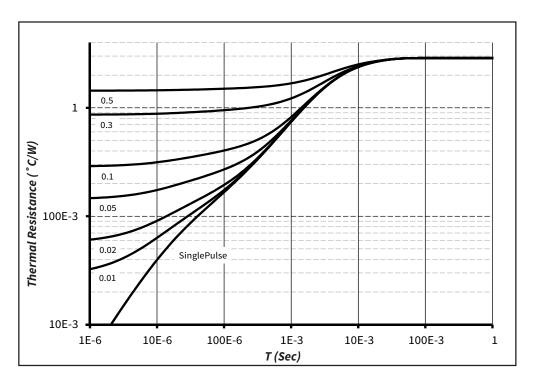
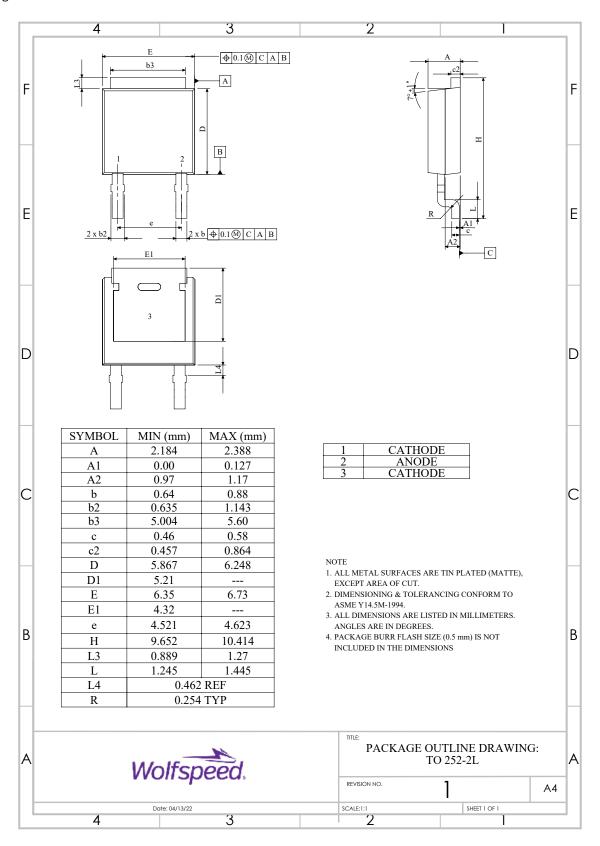


Figure 9. Transient Thermal Impedance

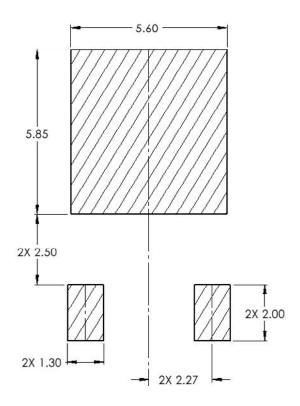


### **Package Dimensions**

Package: TO-252-2



### **Recommended Solder Pad Layout**



| Part Number | Package  | Marking  |
|-------------|----------|----------|
| C3D04060E   | TO-252-2 | C3D04060 |

### **Diode Model**

$$\begin{array}{c|c} + & & \\ \hline + & & \\ \hline + & & \\ \hline V_T & & \\ \hline R_T \end{array}$$

$$Vf_T = V_T + If * R_T$$

$$V_T = 1.00 + (T_J * -1.1*10^{-3})$$

$$R_T = 0.069 + (T_J * 8.3*10^{-4})$$

Note: T<sub>1</sub> = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

### **Revision History**

| Current Revision | Date of Release | Description of Changes  |
|------------------|-----------------|---|
| 10               | September-2023  | Updated Wolfspeed branding, package drawing, and solder pad layout, Removed AEC-Q101 banner |
| 11               | October-2023    | Corrected solder pad layout and diode model   |
| 12               | November - 2024 | Legal Disclaimer  |

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### **Contact info:**

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